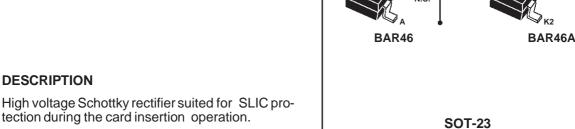


SMALL SIGNAL SCHOTTKY DIODES

(Plastic)

FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- LOW FORWARD VOLTAGE DROP
- SURFACE MOUNT DEVICE



High voltage Schottky rectifier suited for SLIC protection during the card insertion operation.

ABSOLUTE RATINGS(limiting values)

Symbol	Parameter	Value	Unit
VRRM	Repetitive peak reverse voltage	100	V
l _F	Continuous forward current	150	mA
P _{tot}	Power dissipation (note 1)	230	mW
T _{stg}	Maximum storage temperature range	- 65 to +150	°C
Tj	Maximum operating junction temperature *	150	°C
TL	Maximum temperature for soldering during	260	°C

Note 1: for double diodes, Ptot is the total dissipation of both diodes.

* :
$$\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$$
 thermal runaway condition for a diode on its own heatsink

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
Rth(j-a)	Junction-ambient*	500	°C/W

^{*} Mounted on epoxy board, with recommended pad layout.

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BAR46/BAR46A

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test co	Min.	Тур.	Max.	Unit	
V_{BR}	Tj = 25 °C	I _R = 100 μA	100			V
V _F *	Tj = 25 °C	I _F = 0.1 mA			0.25	V
	Tj = 25 °C	I _F = 10 mA			0.45	
	Tj = 25 °C	$I_F = 250 \text{mA}$			1	
I _R **	Tj = 25 °C	V _R = 1.5 V			0.5	μΑ
	Tj = 60 °C				5	
	Tj = 25 °C	V _R = 10 V			0.8	
	Tj = 60 °C				7.5	
	Tj = 25 °C	V _R = 50 V			2	
	Tj = 60 °C				15	
	Tj = 25 °C	V _R = 75 V			5	
	Tj = 60 °C				20	

Pulse test : * tp = $380 \,\mu s$ $\delta < 2\%$ ** tp = 5 ms, $\delta < 2\%$

DYNAMIC CHARACTERISTICS

Symbol	Test conditions			Min.	Тур.	Max.	Unit
С	Tj = 25 °C	V _R = 0 V	F = 1MHz		10		рF
	Tj = 25 °C	V _R = 1 V			6		

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Fig. 1: Forward current versus forward voltage at different temperatures (typical values).

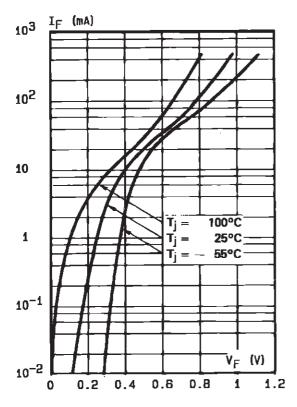


Fig. 3: Reverse current versus junction temperature (typical values).

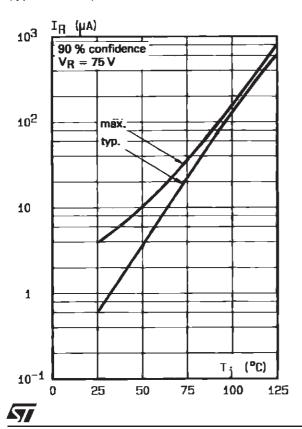


Fig. 2: Forward current versus forward voltage (typical values).

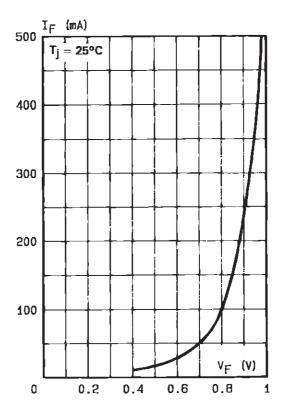
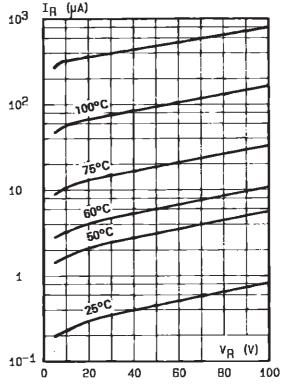
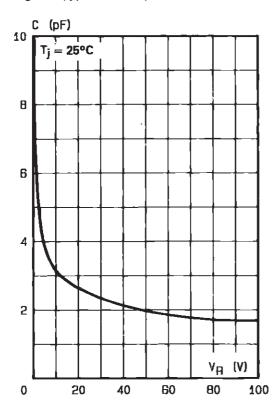


Fig. 4: Reverse current versus continuous reverse voltage (typical values).



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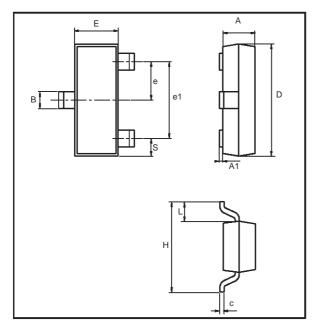
Fig. 5: Capacitance C versus reverse applied voltage V_{R} (typical values).



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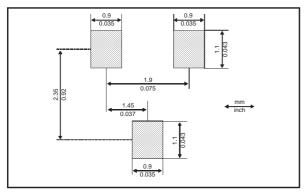
PACKAGE MECHANICAL DATA

SOT 23 (Plastic)



	DIMENSIONS				
REF.	Millin	neters	Inches		
	Min.	Max.	Min.	Max.	
А	0.89	1.4	0.035	0.055	
A1	0	0.1	0	0.004	
В	0.3	0.51	0.012	0.02	
С	0.085	0.18	0.003	0.007	
D	2.75	3.04	0.108	0.12	
е	0.85	1.05	0.033	0.041	
e1	1.7	2.1	0.067	0.083	
E	1.2	1.6	0.047	0.063	
Н	2.1	2.75	0.083	0.108	
L	0.6 typ.		0.024 typ.		
S	0.35	0.65	0.014	0.026	

FOOT PRINT DIMENSIONS (Millimeter)



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
BAR46	S46	SOT-23	0.01g	3000	Tape & reel
BAR46A	A46	SOT-23	0.01g	3000	Tape & reel

■ Epoxy meets UL94,V0

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